## Boosting efficiency above 28% using effective charge transport layer with Sr<sub>3</sub>SbI<sub>3</sub> based novel inorganic perovskite

Md. Shamim Reza<sup>1</sup>, Md. Ferdous Rahman<sup>1\*</sup>, Abdul Kuddus<sup>2\*\*</sup>, Mustafa K. A. Mohammed<sup>3</sup>, Ali K. Al-Mousoi<sup>4</sup>, Md. Rasidul Islam<sup>5</sup>, Avijit Ghosh<sup>1</sup>, Sagar Bhattarai<sup>6</sup>, Rahul Pandey<sup>7</sup>, Jaya Madan<sup>7</sup>, M. Khalid Hossain<sup>8</sup>

<sup>1</sup>Advanced Energy Materials and Solar Cell Research Laboratory, Department of Electrical and Electronic Engineering, Begum Rokeya University, Rangpur 5400, Bangladesh

<sup>2</sup>*Ritsumeikan Global Innovation Research Organization, Ritsumeikan University, Shiga 525-8577, Japan* <sup>3</sup>*College of Engineering, University of Warith Al-Anbiyaa, Karbala 56001, Iraq* 

<sup>4</sup>Electrical Engineering Department, College of Engineering, Al-Iraqia University, Baghdad 10011, Iraq

<sup>5</sup>Department of Electrical and Electronic Engineering, Bangamata Sheikh Fojilatunnesa Mujib Science & Technology University, Jamalpur-2012, Bangladesh

<sup>6</sup>Department of Physics, Arunachal University of Studies, Namsai, 792103, Arunachal Pradesh, India <sup>7</sup>VLSI Centre of Excellence, Chitkara University Institute of Engineering and Technology, Chitkara University, Rajpura 140401 Punjab, India

<sup>8</sup>Institute of Electronics, Atomic Energy Research Establishment, Bangladesh Atomic Energy Commission, Dhaka 1349, Bangladesh

Correspondence: \*ferdousapee@gmail.com (Md. Ferdous Rahman); ORCID: 0000-0002- 0090-2384 \*\*kuddus4910@gmail.com (Abdul Kuddus); ORCID: 0000-0001-5204-3844





(d)



Figure S1. Effects of  $SnS_2$  ETL thickness and bulk defect density variations on photovoltaic parameters; (a)  $V_{OC}$  (b)  $J_{SC}$  (c) FF and (d) PCE.



Figure S2. Influence of (a) hole and (b) electron carrier concentration.